

**B5817W-5819W** SCHOTTKY BARRIER DIODE**FEATURES**

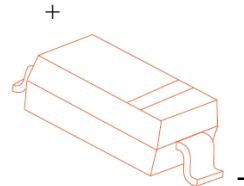
For use in low voltage, high frequency inverters  
Free wheeling, and polarity protection applications.

**MARKING:** B5817W: SJ

B5818W: SK

B5819W: SL

SOD-123

**Maximum Ratings and Electrical Characteristics, Single Diode @T<sub>A</sub>=25°C**

Parameter	Symbol	B5817W	B5818W	B5819W	Unit
Non-Repetitive Peak reverse voltage	V <sub>RM</sub>	20	30	40	V
Peak repetitive Peak reverse voltage	V <sub>RRM</sub>				
Working Peak Reverse Voltage	V <sub>RWM</sub>	20	30	40	V
DC Blocking Voltage	V <sub>R</sub>				
RMS Reverse Voltage	V <sub>R(RMS)</sub>	14	21	28	V
Average Rectified Output Current	I <sub>O</sub>		1		A
Peak forward surge current @=8.3ms	I <sub>FSM</sub>		9		A
Repetitive Peak Forward Current	I <sub>FRM</sub>		1.5		A
Power Dissipation	P <sub>d</sub>		500		mW
Thermal Resistance Junction to Ambient	R <sub>θJA</sub>		250		°C/W
Storage temperature	T <sub>STG</sub>		-65~+150		°C

**ELECTRICAL CHARACTERISTICS (T<sub>amb</sub>=25°C unless otherwise specified)**

Parameter	Symbol	Test conditions	MIN	MAX	UNIT
Reverse breakdown voltage	V <sub>(BR)</sub>	I <sub>R</sub> = 1mA B5817W B5818W B5819W	20 30 40		V
Reverse voltage leakage current	I <sub>R</sub>	V <sub>R</sub> =20V V <sub>R</sub> =30V V <sub>R</sub> =40V B5817W B5818W B5819W		1	mA
Forward voltage	V <sub>F</sub>	B5817W I <sub>F</sub> =1A I <sub>F</sub> =3A		0.45 0.75	V
		B5818W I <sub>F</sub> =1A I <sub>F</sub> =3A		0.55 0.875	V
		B5819W I <sub>F</sub> =1A I <sub>F</sub> =3A		0.6 0.9	V
Diode capacitance	C <sub>D</sub>	V <sub>R</sub> =4V, f=1MHz		120	pF

# Typical Characteristics

**B5817-5819W**

